



**BSI Standards Publication**

## **Semiconductor devices**

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Part 9: Discrete devices – Insulated-gate bipolar transistors (IGBTs)

## National foreword

This British Standard is the UK implementation of IEC 60747-9:2019. It supersedes BS IEC 60747-9:2007, which is withdrawn.

The UK participation in its preparation was entrusted to Technical Committee EPL/47, Semiconductors.

A list of organizations represented on this committee can be obtained on request to its secretary.

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### Amendments/corrigenda issued since publication

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